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FAIRCHILD SEMICONDUCTOR®

2014 年 1 月

FCA16N60N

N 沟道 SupreMOS® MOSFET
600 V, 16 A, 199 mΩ

特性

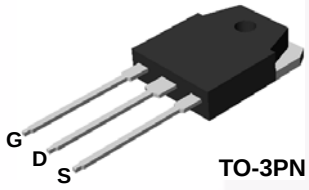
- $R_{DS(on)}$ = 170 mΩ (Typ.) @ V_{GS} = 10V, I_D = 8 A
- 超低栅极电荷 （典型值 Q_g = 40.2 nC）
- 低有效输出电容 （典型值 $C_{oss(eff.)}$= 176 pF）
- 100% 经过雪崩测试
- 符合 RoHS 标准

说明

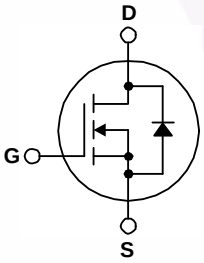
SupreMOS® MOSFET 是飞兆半导体的下一代高压超级结（SJ）技术，该技术采用区别于传统 SJ MOSFET 产品的深沟槽填充工艺。这项先进技术和精密的工艺控制提供了最低的 Rsp on-resistance（导通电阻规格），卓越的开关性能和耐用性。SupreMOS MOSFET 产品非常适合高频开关电源转换器应用，如功率因数校正 (PFC)、服务器 / 电信电源、平板电视电源、ATX 电源及工业电源应用。

应用

- PDP 电视
- AC-DC 电源



TO-3PN



MOSFET 最大额定值针对 T_C = 25°C 除非另有说明。

符号	参数		FCA16N60N	单位
V_{DSS}	漏极－源极电压		600	V
V_{GSS}	栅极－源极电压		±30	V
I_D	漏极电流	- 连续 (T_C = 25°C)	16.0	A
		- 连续 (T_C = 100°C)	10.1	
I_{DM}	漏极电流	- 脉冲 （注 1）	48.0	A
E_{AS}	单脉冲雪崩能量	（注 2）	355	mJ
I_{AR}	雪崩电流	（注 1）	5.3	A
E_{AR}	重复雪崩能量	（注 1）	1.34	mJ
dv/dt	MOSFET dv/dt		100	V/ns
	二极管恢复 dv/dt 峰值	（注 3）	20	V/ns
P_D	功耗	(T_C = 25°C)	134.4	W
		- 超过 25°C 时降额	1.08	W/°C
T_J, T_{STG}	工作和存储温度范围		-55 至 +150	°C
T_L	用于焊接的最大引脚温度，距离外壳 1/8”，持续 5 秒		300	°C

热性能

符号	参数	FCA16N60N	单位
$R_{\theta JC}$	结至外壳热阻最大值	0.93	°C/W
$R_{\theta JA}$	结至环境热阻最大值	40	

封装标识与定购信息

器件编号	顶标	封装	包装方法	卷尺寸	带宽	数量
FCA16N60N	FCA16N60N	TO-3PN	塑料管	不适用	不适用	30 单元

电气特性 T_C = 25°C 除非另有说明。

符号	参数	测试条件	最小值	典型值	最大值	单位
关断特性						
BV_{DSS}	漏极－源极击穿电压	I_D = 1 mA, V_{GS} = 0 V, T_C = 25°C	600	-	-	V
ΔBV_{DSS} / ΔT_J	击穿电压温度系数	I_D = 1 mA，参考 25°C	-	0.73	-	V/°C
I_{DSS}	零栅极电压漏极电流	V_{DS} = 480 V, V_{GS} = 0 V	-	-	10	μA
		V_{DS} = 480 V, V_{GS} = 0 V, T_C = 125°C	-	-	100	
I_{GSS}	栅极 - 体漏电流	V_{GS} = ±30 V, V_{DS} = 0 V	-	-	±100	nA
导通特性						
$V_{GS(th)}$	栅极阈值电压	V_{GS} = V_{DS}, I_D = 250 μA	2.0	-	4.0	V
$R_{DS(on)}$	漏极至源极静态导通电阻	V_{GS} = 10 V, I_D = 8 A	-	0.170	0.199	Ω
g_{FS}	正向跨导	V_{DS} = 40 V, I_D = 8 A	-	20	-	S
动态特性						
C_{iss}	输入电容	V_{DS} = 100 V, V_{GS} = 0 V, f = 1 MHz	-	1630	2170	pF
C_{oss}	输出电容		-	70	95	pF
C_{rss}	反向传输电容		-	5	10	pF
C_{oss}	输出电容	V_{DS} = 380 V, V_{GS} = 0 V, f = 1 MHz	-	40	60	pF
$C_{oss(eff.)}$	有效输出电容	V_{DS} = 0 V 至 480 V, V_{GS} = 0 V	-	176	-	pF
$Q_{g(tot)}$	10 V 的栅极电荷总量	V_{DS} = 380 V, I_D = 8 A, V_{GS} = 10 V （说明 4）	-	40.2	52.3	nC
Q_{gs}	栅极 - 源极栅极电荷		-	6.7	-	nC
Q_{gd}	栅极 - 漏极 “ 密勒 ” 电荷		-	12.9	-	nC
ESR	等效串联电阻 (G-S)	f = 1 MHz	-	2.9	-	Ω
开关特性						
$t_{d(on)}$	导通延迟时间	V_{DD} = 380 V, I_D = 8 A, V_{GS} = 10 V, R_G = 4.7 Ω （说明 4）	-	15.8	41.6	ns
t_r	开通上升时间		-	15.5	41.0	ns
$t_{d(off)}$	关断延迟时间		-	60.3	130.6	ns
t_f	关断下降时间		-	20.2	50.4	ns
漏极 - 源极二极管特性						
I_S	漏极 - 源极二极管最大正向连续电流		-	-	16	A
I_{SM}	漏极 - 源极二极管最大正向脉冲电流		-	-	48	A
V_{SD}	漏极 - 源极二极管正向电压	V_{GS} = 0 V, I_{SD} = 8 A	-	-	1.2	V
t_{rr}	反向恢复时间	V_{GS} = 0 V, I_{SD} = 8 A, dI_F/dt = 100 A/μs	-	319	-	ns
Q_{rr}	反向恢复电荷		-	4.4	-	μC

注意：

1. 重复额定值：脉冲宽度受限于最大结温。
2. I_{AS} = 5.3 A， R_G = 25 Ω，启动 T_J = 25°C。
3. I_{SD} ≤ 16 A， di/dt ≤ 200 A/μs， V_{DD} = 380 V，启动 T_J = 25°C。
4. 本质上独立于工作温度的典型特性。

典型性能特征

图 1. 导通区域特性

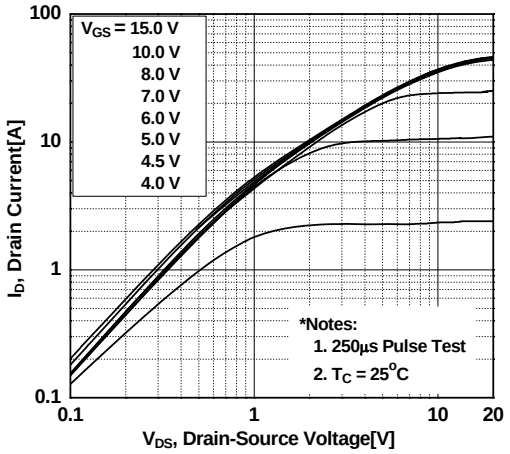


图 2. 传输特性

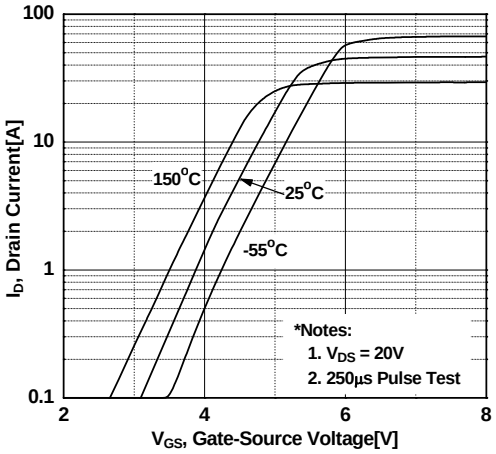


图 3. 导通电阻变化与漏极电流和栅极电压

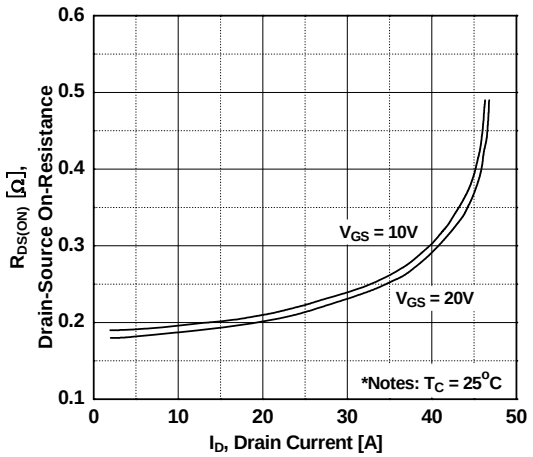


图 4. 体二极管正向电压变化与源极电流和温度

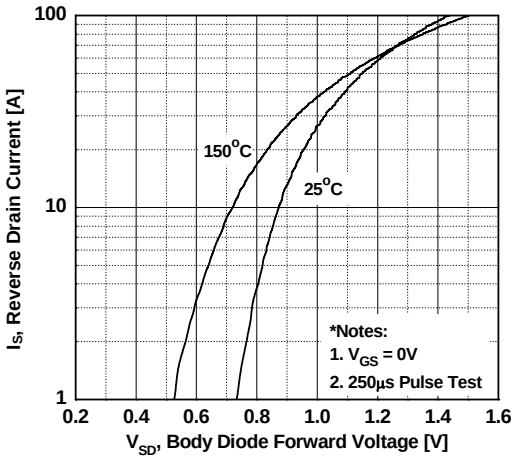


图 5. 电容特性

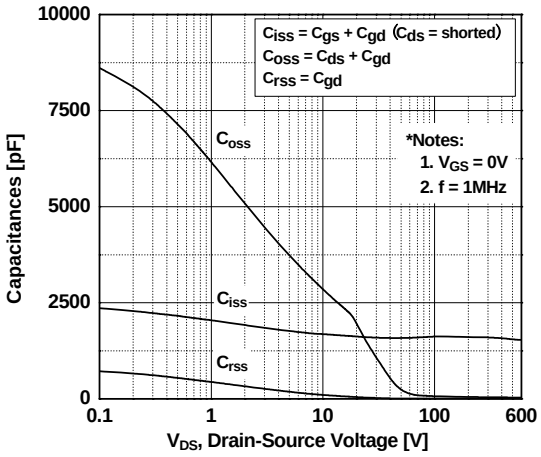
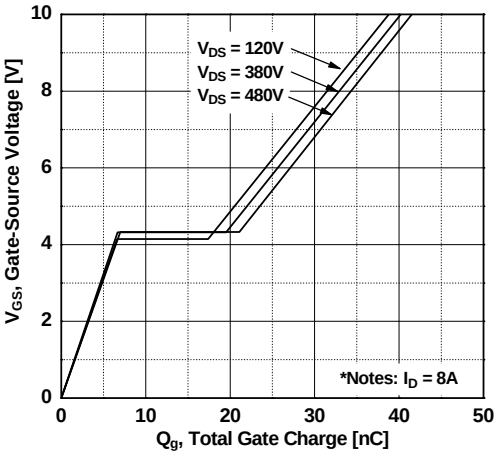


图 6. 栅极电荷



典型性能特征（接上页）

图 7. 击穿电压变化与温度

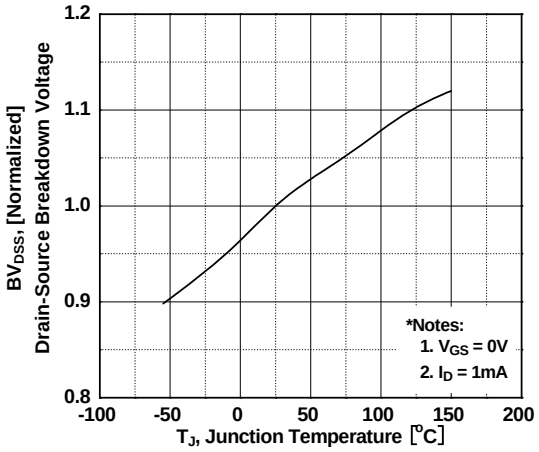


图 8. 导通电阻变化与温度

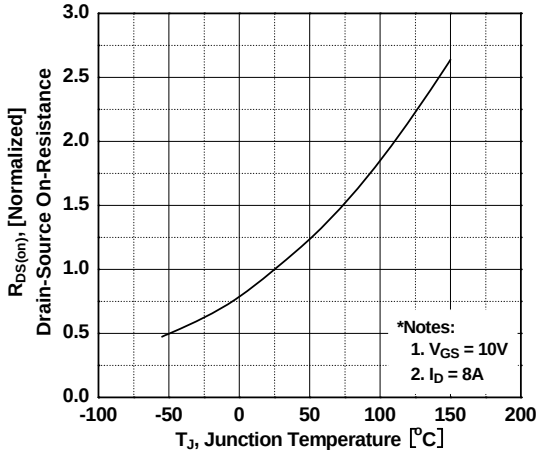


图 9. 最大安全工作区

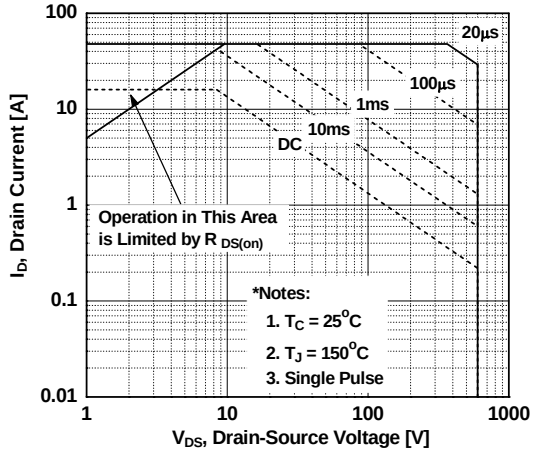


图 10. 最大漏极电流与壳体温度

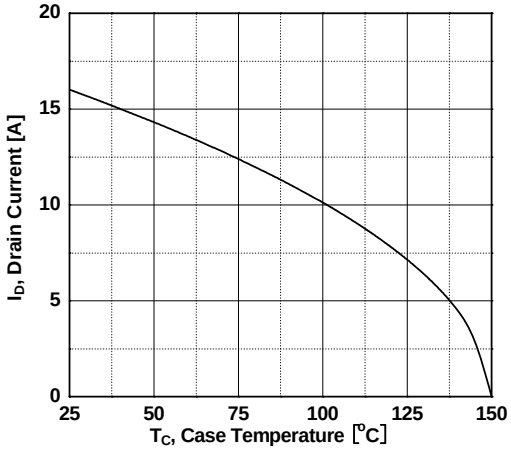
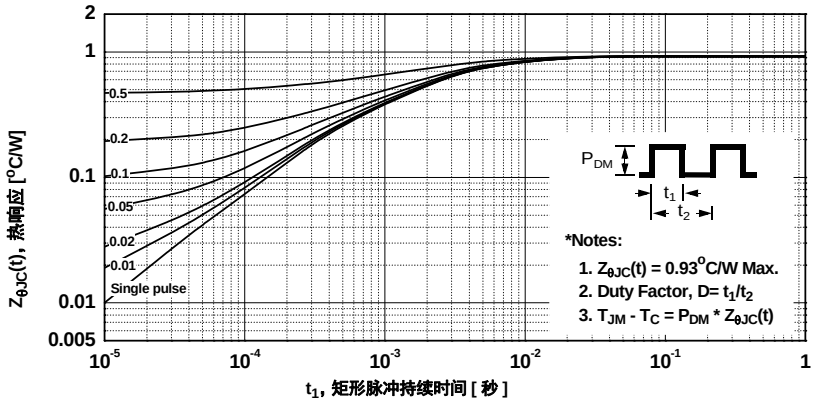


图 11. 瞬态热响应曲线



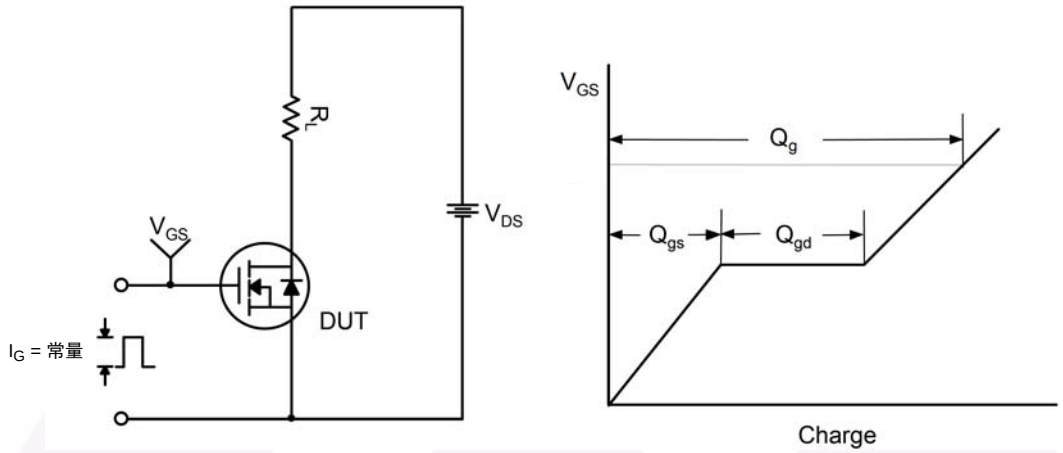


图 12. 栅极电荷测试电路与波形

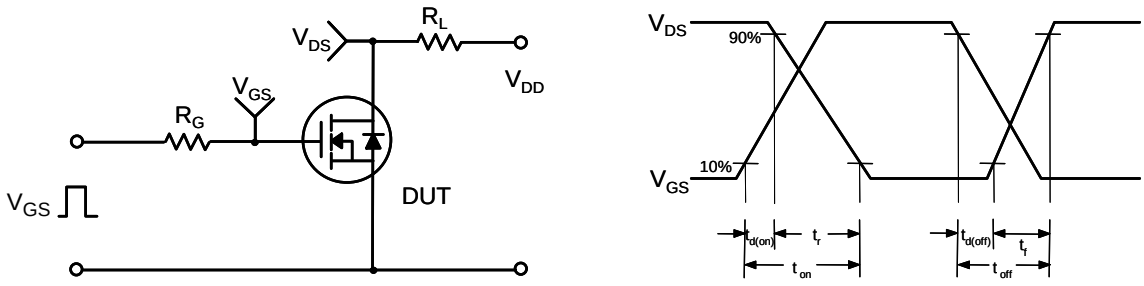


图 13. 阻性开关测试电路与波形

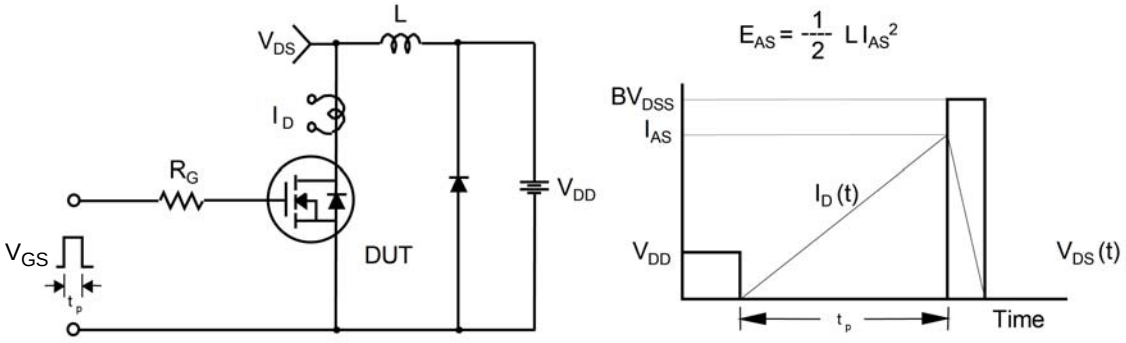


图 14. 非箝位感性开关测试电路与波形

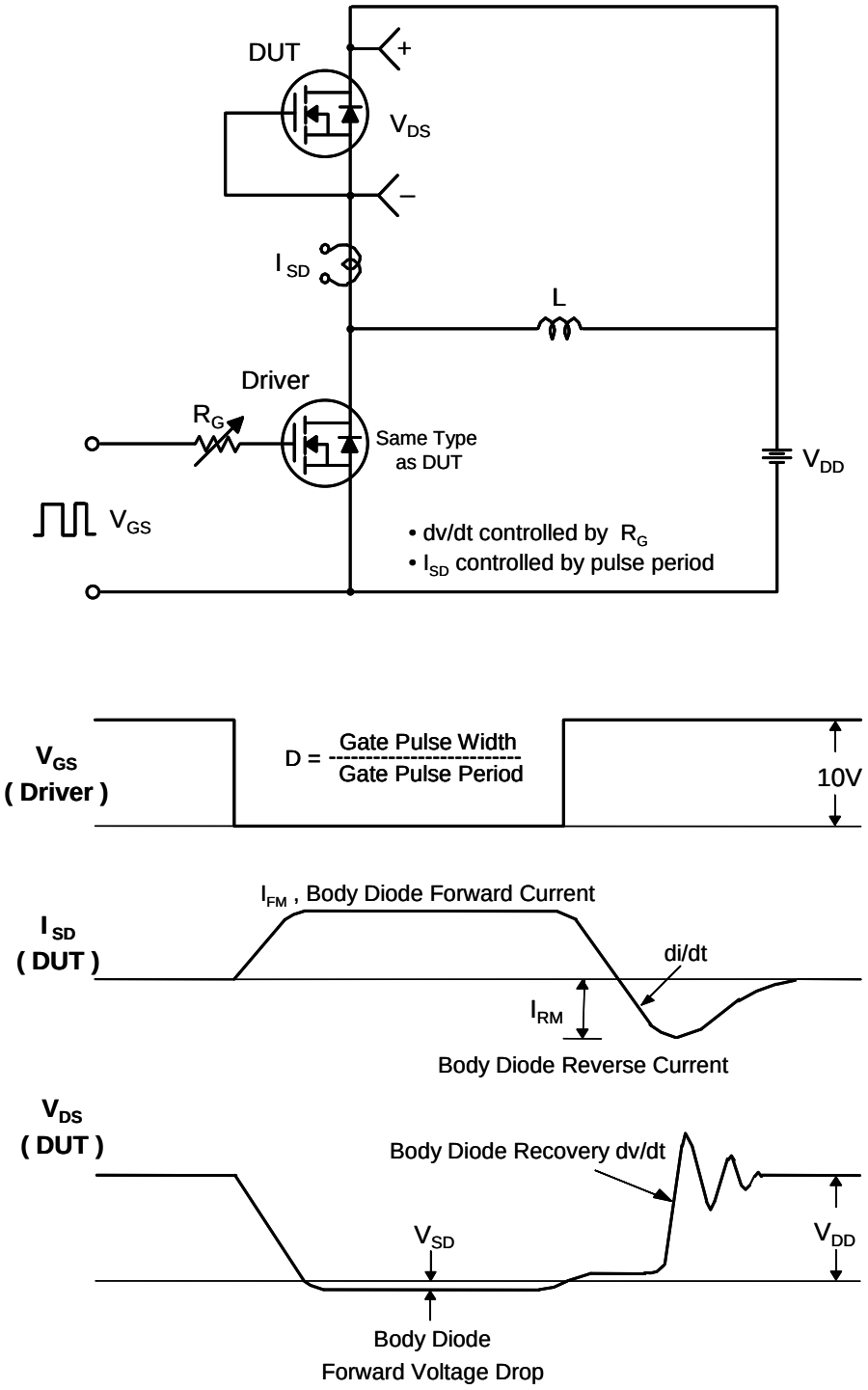


图 15. 二极管恢复 dv/dt 峰值测试电路与波形

机械尺寸

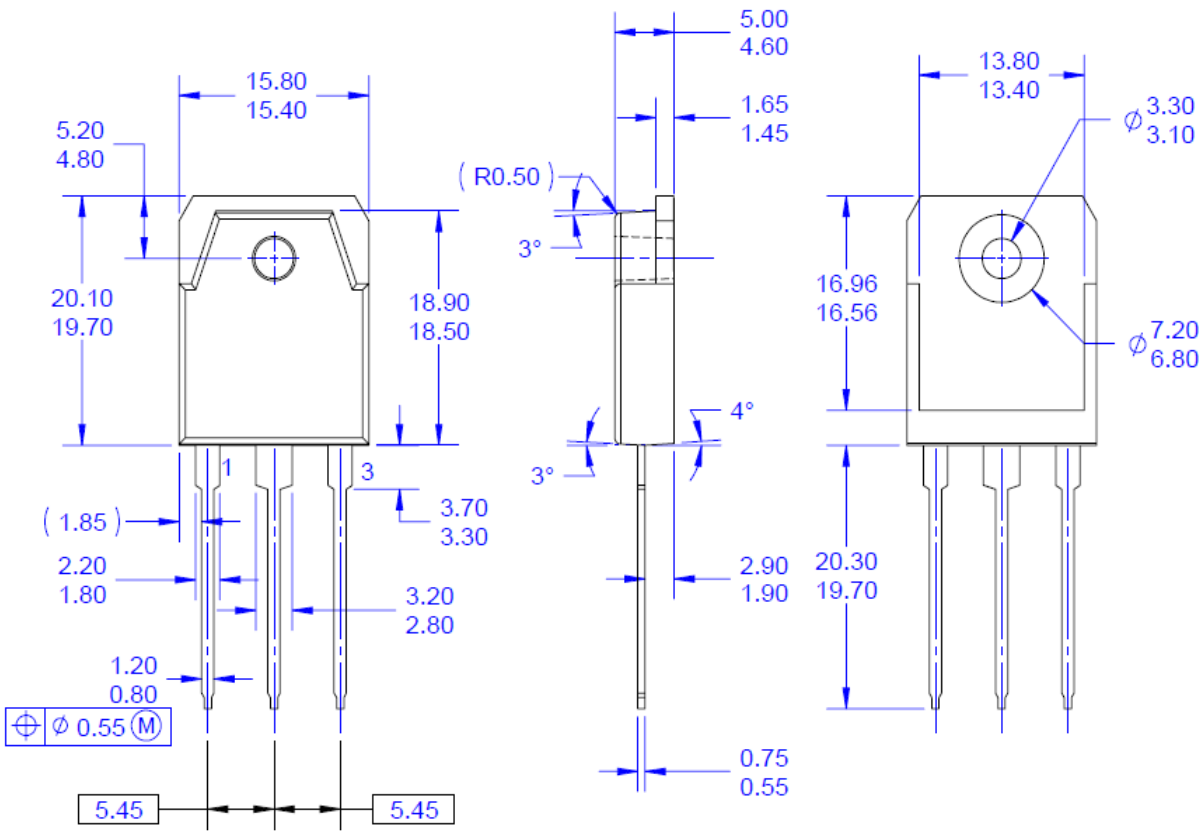


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图 16. TO3， 3 引脚、塑料， EIAJ SC-65

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Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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Rev. I66

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